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## NTE3169, NHTE3170, NTE3171 Square Light Emitting Diode – 5mm

**Description:**

The NTE3169 (Bright Red) source color is made with Gallium Phosphide on a Gallium Phosphide Red Light Emitting Diode. The NTE3170 (Green) is made with Gallium Phosphide on a Gallium Phosphide Green Light Emitting Diode and the NTE3171 (Yellow) is made with Gallium Arsenide Phosphide on a Gallium Phosphide Yellow Light Emitting Diode.

**Features:**

- Low Power Consumption
- Uniform Light Emittance
- I.C Compatible
- Long Life Solid State Reliability

**Absolute Maximum Ratings:** ( $T_A = +25^{\circ}C$  unless otherwise specified)

Power Dissipation	
NTE3169 .....	40mW
Derate Linear from $+25^{\circ}C$ .....	0.2mA/ $^{\circ}C$
NTE3170 .....	100mW
Derate Linear from $+25^{\circ}C$ .....	0.4mA/ $^{\circ}C$
NTE3171 .....	60mW
Derate Linear from $+25^{\circ}C$ .....	0.25mA/ $^{\circ}C$
Peak Forward Current (1/10 Duty Cycle, 0.1ms Pulse Width)	
NTE3169 .....	60mA
NTE3170 .....	120mA
NTE3171 .....	80mA
Continuous Forward Current	
NTE3169 .....	15mA
NTE3170 .....	30mA
NTE3171 .....	20mA
Reverse Voltage .....	5V
Storage and Operating Temperature Range .....	$-55^{\circ}$ to $+100^{\circ}C$
Lead Soldering Temperature (1.6mm From Body for 5 seconds.) .....	$+260^{\circ}C$

Note 1. **NTE3171** is a **discontinued** device and **no longer available**.

**Electro-Optical Characteristics:** ( $T_A = +25^\circ\text{C}$  unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Viewing Angle	$2\theta_{1/2}$	Note 2	-	150	-	deg.
Luminous Intensity NTE3170, NTE3171	$I_V$	$I_F = 10\text{mA}$ (Note 3)	0.5	1.7	-	mcd
NTE3169			0.2	0.6	-	mcd
Peak Emission Wavelength NTE3169	$\lambda_{\text{peak}}$	Measuremeant @ Peak	-	697	-	nm
NTE3170			-	565	-	nm
NTE3171			-	585	-	nm
Spectral Line Half Width NTE3169	$\Delta\lambda$		-	90	-	nm
NTE3170			-	30	-	nm
NTE3171			-	35	-	nm
Forward Voltage	$V_F$	$I_F = 20\text{mA}$	-	2.1	2.8	V
Reverse Current	$I_R$	$V_R = 5\text{V}$	-	-	100	$\mu\text{A}$
Capacitance NTE3169	C	$V_F = 0, f = 1\text{MHz}$	-	55	-	pF
NTE3170			-	35	-	pF
NTE3171			-	15	-	pF

Note 2.  $\theta_{1/2}$  is the off-axis angle at which the luminous intensity is half the axial luminous intensity

Note 3. Luminous intensity is measured with a light sensor and filter combination that approximates the CIE eye-response curve.

